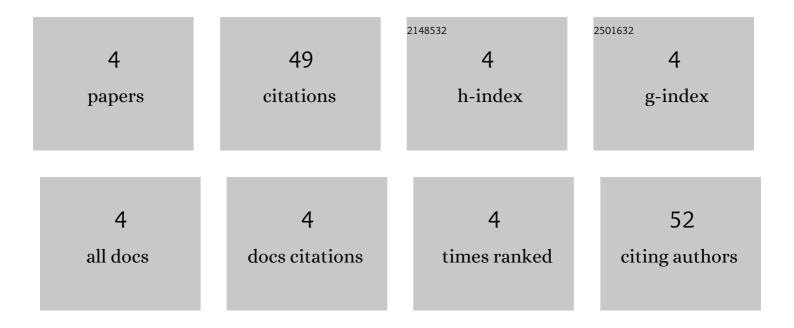
Anli Yang

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/8753271/publications.pdf Version: 2024-02-01



#	Article	IF	CITATIONS
1	Carrier lifetime control by intentional boron doping in aluminum doped p-type 4H-SiC epilayers. Journal of Applied Physics, 2021, 129, .	1.1	6
2	Analysis of carrier lifetimes in N + B-doped <i>n</i> -type 4H-SiC epilayers. Journal of Applied Physics, 2019, 126, .	1.1	15
3	Wide-ranging control of carrier lifetimes in n-type 4H-SiC epilayer by intentional vanadium doping. Journal of Applied Physics, 2019, 126, .	1.1	21
4	Time-resolved photoluminescence spectral analysis of phonon-assisted DAP and e-A recombination in N+B-doped n-type 4H-SiC epilayers. Journal Physics D: Applied Physics, 2019, 52, 10LT01.	1.3	7